

HAT2201WP

Silicon N Channel Power MOS FET Power Switching

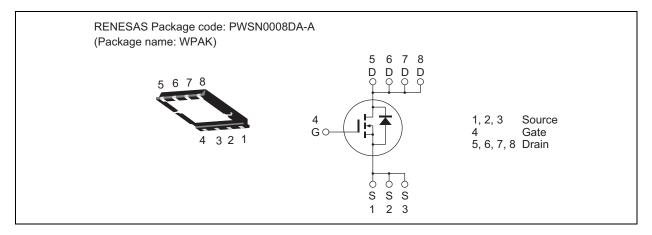
REJ03G1679-0300 Rev.3.00 May 27, 2008

Features

- Capable of 8 V gate drive
- · Low drive current
- High density mounting
- Low on-resistance

 $R_{DS(on)} = 34 \text{ m}\Omega \text{ typ. (at } V_{GS} = 10 \text{ V})$

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	100	V
Gate to source voltage	V_{GSS}	±20	V
Drain current	I _D	15	А
Drain peak current	I _{D(pulse)} Note1	60	А
Body-drain diode reverse drain current	I _{DR}	15	Α
Avalanche current	I _{AP} Note 2	15	А
Avalanche energy	E _{AR} Note 2	22.5	mJ
Channel dissipation	Pch Note3	15	W
Channel to case thermal Impedance	θch-c Note3	8.33	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	−55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tch = 25°C, Rg \geq 50 Ω

3. Tc = 25°C

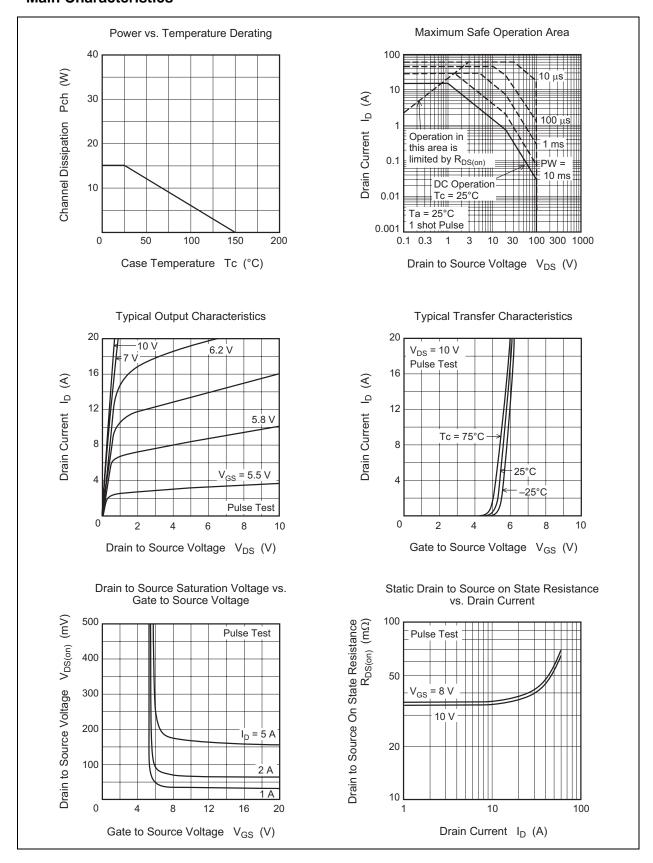
Electrical Characteristics

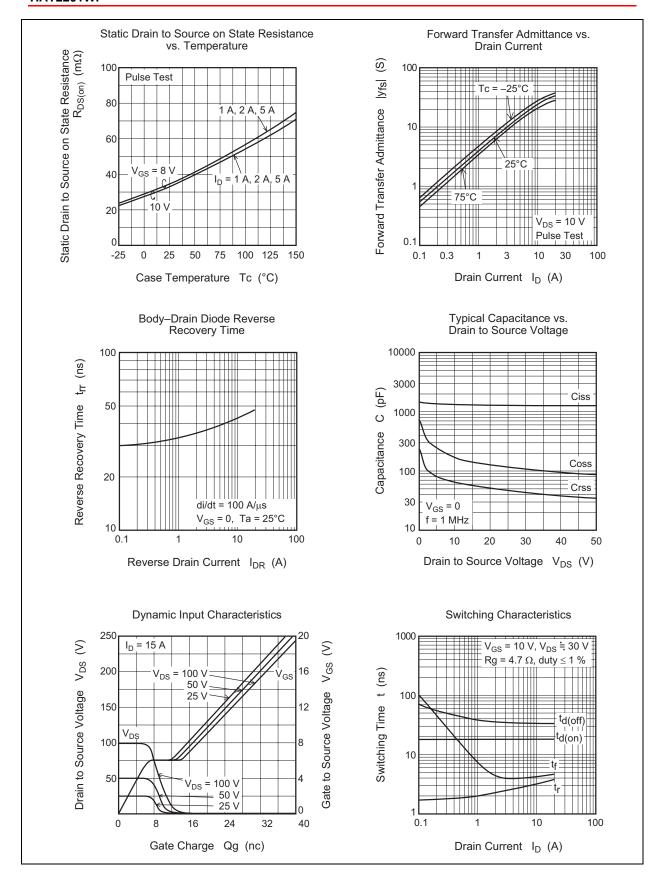
 $(Ta = 25^{\circ}C)$

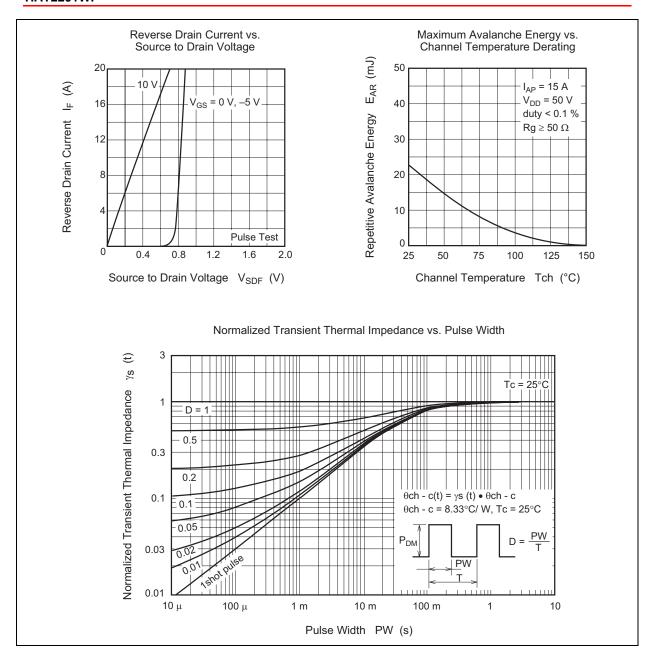
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	100	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I_{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}		_	1	μΑ	$V_{DS} = 100 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	3.5	_	5.0	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	34	43	mΩ	$I_D = 7.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance	R _{DS(on)}	_	35	49	mΩ	$I_D = 7.5 \text{ A}, V_{GS} = 8 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	12	20	_	S	$I_D = 7.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	1450	_	pF	V _{DS} = 10 V
Output capacitance	Coss	_	180	_	pF	V _{GS} = 0
Reverse transfer capacitance	Crss	_	65	_	pF	f = 1 MHz
Gate resistance	Rg	_	0.9	_	Ω	
Total gate charge	Qg	_	21	_	nc	$V_{DD} = 50 \text{ V}$
Gate to source charge	Qgs	_	7.6	_	nc	V _{GS} = 10 V
Gate to drain charge	Qgd	_	5.2	_	nc	I _D = 15 A
Turn-on delay time	t _{d(on)}	_	18	_	ns	$V_{GS} = 10 \text{ V}, I_D = 7.5 \text{ A}$
Rise time	t _r	_	3	_	ns	$V_{DD} \cong 30 \text{ V}$
Turn-off delay time	t _{d(off)}	_	33	_	ns	$R_L = 4 \Omega$
Fall time	t _f	_	4.1	_	ns	$Rg = 4.7 \Omega$
Body-drain diode forward voltage	V_{DF}	_	0.84	1.10	V	$I_F = 15 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery	t _{rr}	_	45	_	ns	I _F = 15 A, V _{GS} = 0
time						di _F / dt = 100 A/ μs

Notes: 4. Pulse test

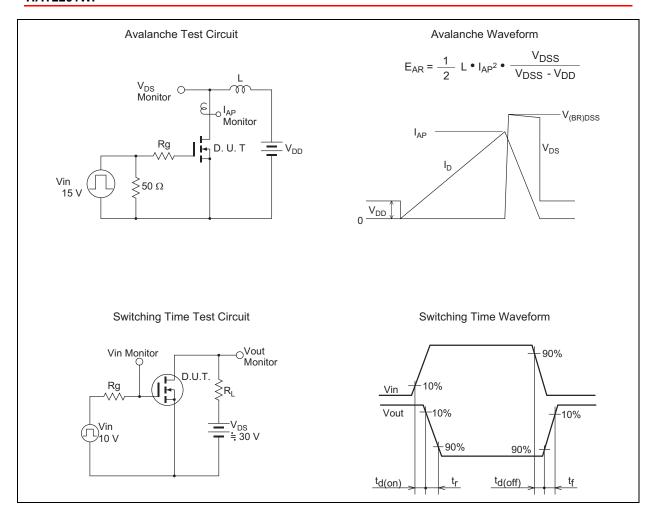
Main Characteristics



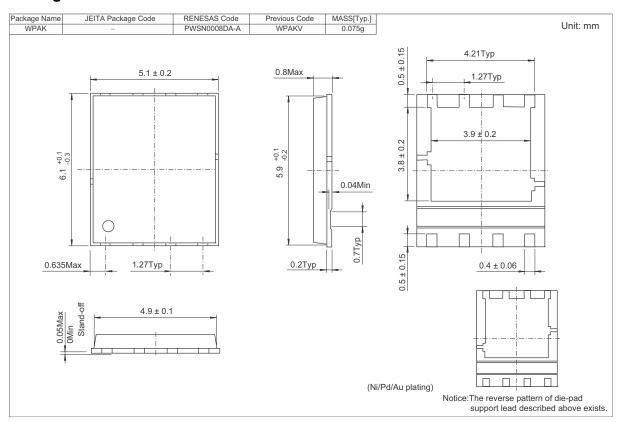




RENESAS



Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
HAT2201WP-EL-E	2500 pcs	Taping

Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

- Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

 Notes:

 1. This document is provided for reference purposes only so that Penesas customers may select the appropriate Renesas products for their use. Renesas neither makes in the reference purposes only so that Penesas customers may select the appropriate Renesas products for their use. Renesas neither makes are all to the source of the product of the reseas of the information in this document nor grants any license to any intellectual property rights or any other rights of Renesas or any third party with respect to the information in this document nor grants any license to any intellectual property or other rights arising out of the use of any information in this document, including, but not limited to, product data, diagrams, charts, programs, algorithms, and application circuit examples.

 3. You should not use the products or the technology described in this document for the purpose of military applications such as the development of waspons of mass and application circuit examples, is current as of the date this document in included in this document such as product data, diagrams, charts, programs, algorithms, and application circuit examples, is current as of the date this document is issued. Such information however, is subject to change without any prior notice. Before purchasing or using any Renesas products itself in this document, but all information in included in this document, but application control laws and products of the products of the products of the date this document, but application and careful attention to additional and different information in the date this document, but applications on the latest product information where the subject to change without any prior notice. Before purchase resisted in this document, but applications are products as a few products of the produ



RENESAS SALES OFFICES

http://www.renesas.com

Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

Renesas Technology America, Inc.

450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2377-3473

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399

Renesas Technology Singapore Pte. Ltd. 1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

L		